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B.M.S. College of Engineering, Bengaluru-560019

Autonomous Institute Affiliated to VTU

July 2023 Semester End Main Examinations

Programme: B.E.

Branch: Medical Electronics Engineering

Course Code: 19ML6PE3VS

Course: VLSI and SoC Design

Semester: VI

Duration: 3 hrs.

Max Marks: 100

Date: 17.07.2023

Instructions: 1. Answer any FIVE full questions, choosing one full question from each unit.
2. Missing data, if any, may be suitably assumed.

| | | | UNIT - I | CO | PO | Marks |
|---|----|--|-------------------|------------|------------|--------------|
| 1 | a) | Describe the functions of MOSFETs as a Switch. | | <i>CO1</i> | <i>PO1</i> | 05 |
| | b) | Explain the working of a Complementary Metal Oxide Semiconductor (CMOS) Inverter and NOR gate. | | <i>CO2</i> | <i>PO2</i> | 10 |
| | c) | Implement XOR gate logic using Transmission gate. | | <i>CO3</i> | <i>PO3</i> | 05 |
| | | | UNIT - II | | | |
| 2 | a) | Describe the layers used to create MOSFET with suitable diagram. | | <i>CO2</i> | <i>PO2</i> | 06 |
| | b) | Design a CMOS circuit for 4input AOI expression $F = \bar{x} \cdot y + z \cdot w$ | | <i>CO3</i> | <i>PO3</i> | 04 |
| | c) | With cross-sectional view, Illustrate CMOS device with MOSFETs layers in an n-well process on p substrate. | | <i>CO2</i> | <i>PO2</i> | 10 |
| | | | UNIT - III | | | |
| 3 | a) | Derive an Expression for Drain current flowing in a MOSFET. | | <i>CO2</i> | <i>PO2</i> | 10 |
| | b) | With suitable circuit diagram and graphs, Analyze the Transient characteristics of CMOS Inverter circuit. | | <i>CO3</i> | <i>PO3</i> | 10 |
| | | | OR | | | |
| 4 | a) | Derive an expression for total dynamic power dissipation in a network consisting of N number of gates. | | <i>CO2</i> | <i>PO2</i> | 10 |
| | b) | Discuss the transient response of a 2input NAND gate. | | <i>CO2</i> | <i>PO2</i> | 10 |
| | | | UNIT - IV | | | |
| 5 | a) | Define SOC. Discuss and Compare SOC, SIP and SOB. | | <i>CO1</i> | <i>PO1</i> | 10 |
| | b) | What is the significance of 'reusable macros' (IP) in the designing of SOC? Explain various types of reusable macros (IP) used in SOC. | | <i>CO2</i> | <i>PO2</i> | 10 |

Important Note: Completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages. Revealing of identification, appeal to evaluator will be treated as malpractice.

| OR | | | | | |
|-----------------|----|---|------------|------------|-----------|
| 6 | a) | Define the term “Design productivity gap”. Also discuss the effect of this on time to market with suitable graph. | <i>CO2</i> | <i>PO2</i> | 10 |
| | b) | Define Moore’s law. Elaborate on the limitations imposed by small device geometrics? | <i>CO2</i> | <i>PO2</i> | 10 |
| UNIT - V | | | | | |
| 7 | a) | With the help of neat diagram, Explain the principle of Waterfall design flow used in SOC. | <i>CO2</i> | <i>PO2</i> | 10 |
| | b) | Explain the system design process in detail. | <i>CO2</i> | <i>PO2</i> | 10 |

B.M.S.C.E. - EVEN SEM 2022-23